Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

**Overall Length:** 

2.375 inches

Mounting Facility Quantity:

1

### Mounting Method:

Threaded stud

**Features Provided:** 

Hermetically sealed case

### **Overall Width Across Flats:**

Between 1.605 inches and 1.641 inches

**Thread Size:** 

0.750 inches

Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

1200.0 repetitive peak off-state voltage

# **Current Rating Per Characteristic:**

470.00 amperes forward current, total rms nanoamperes

## **Power Rating Per Characteristic:**

3.0 watts small-signal input power, common-collector blank

## Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

## **Thread Series Designator:**

Unf

### **Terminal Type And Quantity:**

1 threaded stud and 2 tab, solder lug

Shelf Life:

N/a

### Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0